NSN 5962-01-323-4953

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-323-4953 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.150 inches and 0.210 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 22 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Current Rating Per Characteristic:** 10.00 milliamperes supply **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.3 volts power source and 7.0 volts power source **Memory Device Type:** Ram **Memory Capacity:** Unknown **Test Data Document:** 81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:**

Shelf Life:

24 printed circuit

Specification Data:

81349-mil-m-38510/291 government specification

N/a

NSN 5962-01-323-4953

Memory Microcircuit - Page 2 of 2



Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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